PNP Epitaxial Silicon Transistor

KSA928A

Features

- Audio Power Amplifier
- Complement to KSC2328A
- 3 W Output Application

ABSOLUTE MAXIMUM RATINGS

(Values are at $T_A = 25^{\circ}$ C unless otherwise noted.) (Notes 1, 2)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-30	V
V _{CEO}	Collector-Emitter Voltage	-30	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-2	Α
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

THERMAL CHARACTERISTICS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.) (Note 3)

Symbol	Parameter	Value	Unit
P_{D}	Power Dissipation	1000	mW
	Derate Above 25°C	8.0	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	125	°C/W

3. PCB size: FR-4, 76 mm \times 114 mm \times 1.57 mm (3.0 inch \times 4.5 inch \times 0.062 inch) with minimum land pattern size.



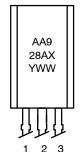
ON Semiconductor®

www.onsemi.com



TO-92 3 LF CASE 135AM

MARKING DIAGRAM



- 1: Emitter
- 2: Collector
- 3: Base

= Assembly Code A928A = Device Code = O/Y= Date Code

ORDERING INFORMATION

Device	Package	Shipping
KSA928AOTA	TO-92 3 LF (Pb-Free)	2000 / Fan–Fold
KSA928AYTA	TO-92 3 LF (Pb-Free)	2000 / Fan-Fold

KSA928A

ELECTRICAL CHARACTERISTICS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = -100 \mu A, I_E = 0$	-30	-	-	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -10 \text{ mA}, I_B = 0$	-30	-	-	V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -1 \text{ mA}, I_C = 0$	-5	-	-	V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = -30 \text{ V}, I_{E} = 0$	-	-	-100	nA
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = -5 \text{ V}, I_C = 0$	-	-	-100	nA
h _{FE}	DC Current Gain	$V_{CE} = -2 \text{ V}, I_{C} = -500 \text{ mA}$	100	-	320	
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = -2 \text{ V}, I_{C} = -500 \text{ mA}$	-	-	-1.0	V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -1.5 \text{ A}, I_B = -30 \text{ mA}$	-	-	-2.0	V
f _T	Current Gain Bandwidth Product	$V_{CE} = -2 \text{ V}, I_{C} = -500 \text{ mA}$	-	120	-	MHz
C _{ob}	Collector Output Capacitance	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	-	48	_	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

hFE CLASSIFICATION

Classification	0	Y
h _{FE}	100 ~ 200	160 ~ 320

KSA928A

TYPICAL PERFORMANCE CHARACTERISTICS

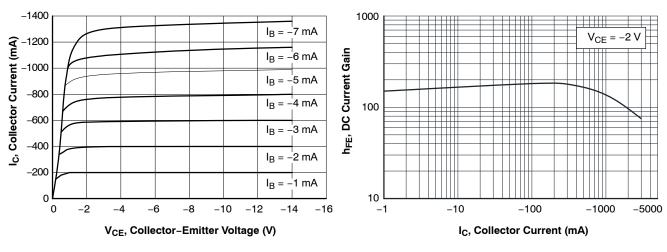


Figure 1. Static Characteristic

Figure 2. DC Current Gain

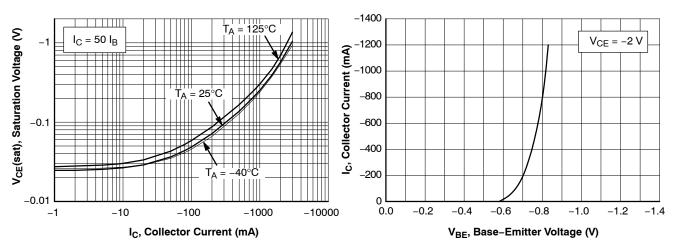
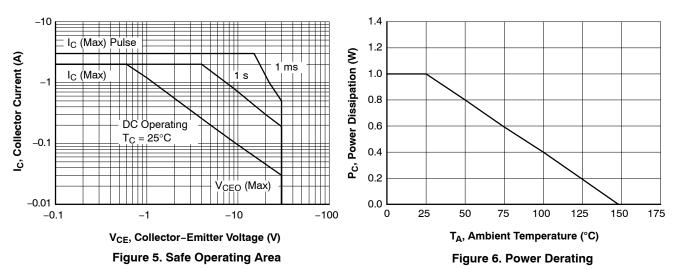
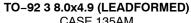


Figure 3. Collector-Emitter Saturation Voltage

Figure 4. Base-Emitter On Voltage





CASE 135AM ISSUE B

DATE 14 JAN 2021



- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, GATE REMAINS AND TIE BAR PROTRUSIONS.
- 4. DIMENSION & AND &2 DOES NOT INCLUDE DAMBAR PROTRUSION.
 DIMENSION &2 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	3.70	3.90	4.10	
A1	1.25	1.45	1.65	
b	0.35	0.50	0.60	
b2	0.62		0.78	
С	0.35	0.45	0.55	
D	7.80	8.00	8.20	
Ε	4.70	4.90	5.10	
E2	3.70	3.90	4.10	
е	1.27 BSC			
e2		2.50 BSC		
F		2.45 REF		
L		13.00 REF		
L2	1.50		1.90	
L3	2.60		3,40	
L4	10.40 REF			

	► A	
	E-E	
	1 1	
_	D B	
L3 L2	h	
1	3	
L'4	e2	
<u>•</u>		7
T	ip view	_

	IUP VIEW	
	E2 	rA1
A	1 2 3	1
	F	

END VIEW

DOCUMENT NUMBER:	IUMBER: 98AON14058G Electronic versions are uncontrolled except when accessed directly from the Docume Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in re		
DESCRIPTION:	TO-92 3 8.0X4.9 (LEADFORMED)		PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative